## SWITCHMODETM

NPN Bipolar Power Transistor
For Switching Power Supply Applications

The BUL44 have an applications specific state-of-the-art die designed for use in 220 V line operated Switchmode Power supplies and electronic light ballasts. These high voltage/high speed transistors offer the following:

- Improved Efficiency Due to Low Base Drive Requirements:

High and Flat DC Current Gain hFE
Fast Switching
No Coil Required in Base Circuit for Turn-Off (No Current Tail)

- Full Characterization at $125^{\circ} \mathrm{C}$
- Tight Parametric Distributions are Consistent Lot-to-Lot


## MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
| :---: | :---: | :---: | :---: |
| Collector-Emitter Sustaining Voltage | $\mathrm{V}_{\text {CEO }}$ | 400 | Vdc |
| Collector-Emitter Breakdown Voltage | $\mathrm{V}_{\text {CES }}$ | 700 | Vdc |
| Emitter-Base Voltage | $\mathrm{V}_{\text {EBO }}$ | 9.0 | Vdc |
| $\begin{array}{r} \text { Collector Current — Continuous } \\ \text { - Peak(1) } \end{array}$ | $\begin{aligned} & \text { IC } \\ & \text { ICM } \end{aligned}$ | $\begin{aligned} & 2.0 \\ & 5.0 \end{aligned}$ | Adc |
| Base Current - Continuous -Peak(1) | $\begin{gathered} \hline \text { IB } \\ \text { IBM } \end{gathered}$ | $\begin{aligned} & 1.0 \\ & 2.0 \end{aligned}$ | Adc |
| Total Device Dissipation Derate above $25^{\circ} \mathrm{C}$$\quad\left(\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}\right)$ | $\mathrm{P}_{\mathrm{D}}$ | $\begin{aligned} & 50 \\ & 0.4 \end{aligned}$ | Watts $\mathrm{W} /{ }^{\circ} \mathrm{C}$ |
| Operating and Storage Temperature | $\mathrm{T}_{\mathrm{J},} \mathrm{T}_{\text {stg }}$ | -65 to 150 | ${ }^{\circ} \mathrm{C}$ |

THERMAL CHARACTERISTICS

| Rating | Symbol | Max | Unit |
| :---: | :---: | :---: | :---: |
| Thermal Resistance <br> — Junction to Case <br> - Junction to Ambient | $\mathrm{R}_{\theta \mathrm{JC}}$ | $\mathrm{R}_{\theta \mathrm{JA}}$ | 62.5 |
| Maximum Lead Temperature for Soldering <br> Purposes: $1 / 8{ }^{\prime \prime}$ from Case for 5 Seconds | $\mathrm{T}_{\mathrm{L}}$ | 260 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## BUL44

ELECTRICAL CHARACTERISTICS ( $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |  |
| Collector-Emitter Sustaining Voltage ( $\mathrm{I} \mathrm{C}=100 \mathrm{~mA}, \mathrm{~L}=25 \mathrm{mH}$ ) | $\mathrm{V}_{\text {CEO }}$ (sus) | 400 | - | - | Vdc |
| Collector Cutoff Current ( $\mathrm{V}_{\mathrm{CE}}=$ Rated $\mathrm{V}_{\mathrm{CEO}}$, $\mathrm{I}_{\mathrm{B}}=0$ ) | ICEO | - | - | 100 | $\mu \mathrm{Adc}$ |
| $\begin{aligned} & \hline \text { Collector Cutoff Current }\left(\mathrm{V}_{\mathrm{CE}}=\text { Rated } \mathrm{V}_{\mathrm{CES}}, \mathrm{~V}_{\mathrm{EB}}=0\right) \\ &\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ &\left(\mathrm{V}_{\mathrm{CE}}=500 \mathrm{~V}, \mathrm{~V}_{\mathrm{EB}}=0\right)\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \end{aligned}$ | ICES | - | - | $\begin{aligned} & 100 \\ & 500 \\ & 100 \end{aligned}$ | $\mu \mathrm{Adc}$ |
| Emitter Cutoff Current ( $\mathrm{V}_{\mathrm{EB}}=9.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0$ ) | IEBO | - | - | 100 | $\mu \mathrm{Adc}$ |

## ON CHARACTERISTICS

| Base-Emitter Saturation Voltage ( $\mathrm{I} \mathrm{C}=0.4 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=40 \mathrm{mAdc}$ ) $\left(I_{C}=1.0 \mathrm{Adc}, I_{B}=0.2 \mathrm{Adc}\right)$ | $\mathrm{V}_{\mathrm{BE}}$ (sat) | - | $\begin{aligned} & 0.85 \\ & 0.92 \end{aligned}$ | $\begin{gathered} 1.1 \\ 1.25 \end{gathered}$ | Vdc |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{array}{ll} \hline \begin{array}{l} \text { Collector-Emitter Saturation Voltage } \\ \left(\mathrm{I}_{\mathrm{C}}=0.4 \text { Adc, } \mathrm{I}_{\mathrm{B}}=40 \mathrm{mAdc}\right) \end{array} & \\ \left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=0.2 \mathrm{Adc}\right) & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ \hline \end{array}$ | $\mathrm{V}_{\text {CE (sat) }}$ | $\begin{aligned} & - \\ & - \\ & - \\ & \hline \end{aligned}$ | $\begin{aligned} & 0.20 \\ & 0.20 \\ & 0.25 \\ & 0.25 \end{aligned}$ | $\begin{aligned} & 0.5 \\ & 0.5 \\ & 0.6 \\ & 0.6 \end{aligned}$ | Vdc |
| $\begin{array}{ll} \begin{array}{ll} \text { DC Current Gain } \\ \left(\mathrm{IC}_{\mathrm{C}}=0.2 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=0.4 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=1.0 \mathrm{Vdc}\right) & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ \left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) & \\ \hline \end{array} \\ \hline \end{array}$ | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 14 \\ & \hline 12 \\ & 12 \\ & 8.0 \\ & 7.0 \\ & 10 \\ & \hline \end{aligned}$ | $\begin{aligned} & 32 \\ & 20 \\ & 20 \\ & 14 \\ & 13 \\ & 22 \end{aligned}$ | 34 | - |

## DYNAMIC CHARACTERISTICS

| Current Gain Bandwidth ( $\mathrm{I}_{\mathrm{C}}=0.5 \mathrm{Adc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{f}=1.0 \mathrm{MHz}$ ) |  |  |  | $\mathrm{f}^{\text {T }}$ | - | 13 | - | MHz |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Output Capacitance ( $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}$ ) |  |  |  | $\mathrm{C}_{\mathrm{OB}}$ | - | 38 | 60 | pF |
| Input Capacitance ( $\mathrm{V}_{\mathrm{EB}}=8.0 \mathrm{~V}$ ) |  |  |  | $\mathrm{ClB}_{1 \mathrm{~B}}$ | - | 380 | 600 | pF |
| Dynamic Saturation Voltage: Determined $1.0 \mu \mathrm{~s}$ and $3.0 \mu \mathrm{~s}$ respectively after rising $\mathrm{I}_{\mathrm{B} 1}$ reaches $90 \%$ of final lB1 | $\begin{aligned} & (\mathrm{I} \mathrm{C}=0.4 \mathrm{Adc} \\ & \mathrm{I}_{\mathrm{B} 1}=40 \mathrm{mAdc} \\ & \left.\mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V}\right) \end{aligned}$ | 1.0 $\mu \mathrm{~s}$ | $\left(\mathrm{T}^{\text {C }}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{V}_{\mathrm{CE}}$ (dsat) | - | 2.5 2.7 | - | Vdc |
|  |  | $\begin{aligned} & 3.0 \\ & \mu \mathrm{~s} \\ & \hline \end{aligned}$ | $\left(\mathrm{T} \mathrm{C}=125^{\circ} \mathrm{C}\right.$ ) |  |  | $\begin{gathered} 1.3 \\ 1.15 \\ \hline \end{gathered}$ |  |  |
|  | $\begin{aligned} & (\mathrm{IC}=1.0 \mathrm{Adc} \\ & \mathrm{IB1}=0.2 \mathrm{Adc} \\ & \mathrm{~V} \mathrm{CC}=300 \mathrm{~V}) \end{aligned}$ | $\begin{aligned} & 1.0 \\ & \mu \mathrm{~s} \\ & \hline \end{aligned}$ | $\left(\mathrm{T} \mathrm{C}=125^{\circ} \mathrm{C}\right.$ ) |  |  | $\begin{aligned} & 3.2 \\ & 7.5 \end{aligned}$ | - |  |
|  |  | 3.0 $\mu \mathrm{s}$ | $\left(\mathrm{T} \mathrm{C}=125^{\circ} \mathrm{C}\right)$ |  | - | 1.25 1.6 | - |  |

(1) Pulse Test: Pulse Width $=5.0 \mathrm{~ms}$, Duty Cycle $\leq 10 \%$.
(continued)

## BUL44

SWITCHING CHARACTERISTICS: Resistive Load (D.C. $\leq 10 \%$, Pulse Width $=20 \mu \mathrm{~s}$ )

| Turn-On Time | ( $\mathrm{I}_{\mathrm{C}}=0.4 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=40 \mathrm{mAdc}$ <br> $\mathrm{I}_{\mathrm{B} 2}=0.2 \mathrm{Adc}, \mathrm{V}_{\mathrm{CC}}=300 \mathrm{~V}$ ) <br> ( $\mathrm{I} \mathrm{C}=0.4 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=40 \mathrm{mAdc}$ <br> $\mathrm{I}_{\mathrm{B} 2}=0.2 \mathrm{Adc}, \mathrm{V}_{\mathrm{CC}}=300 \mathrm{~V}$ ) | $\begin{aligned} & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \\ & \left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right) \end{aligned}$ | $\mathrm{t}_{\mathrm{O}}$ |  | 40 40 | 100 | ns |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Turn-Off Time |  |  | $\mathrm{t}_{\text {off }}$ |  | $\begin{aligned} & 1.5 \\ & 2.0 \end{aligned}$ | 2.5 | $\mu \mathrm{s}$ |
| Turn-On Time | $\begin{aligned} & \left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=0.2 \mathrm{Adc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 1}=0.5 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=0.2 \mathrm{Adc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 2}=0.5 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CC}}=300 \mathrm{~V}\right) \end{aligned}$ | $\begin{aligned} & \left(T_{C}=125^{\circ} \mathrm{C}\right) \\ & \left(T_{C}=125^{\circ} \mathrm{C}\right) \end{aligned}$ | ton | - | 85 85 | 150 | ns |
| Turn-Off Time |  |  | $\mathrm{t}_{\text {off }}$ |  | $\begin{aligned} & 1.75 \\ & 2.10 \end{aligned}$ | 2.5 | $\mu \mathrm{s}$ |

SWITCHING CHARACTERISTICS: Inductive Load (V ${ }_{\text {clamp }}=300 \mathrm{~V}, \mathrm{~V}_{\mathrm{CC}}=15 \mathrm{~V}, \mathrm{~L}=200 \mu \mathrm{H}$ )

| Fall Time | $\begin{aligned} & \left(\mathrm{I} \mathrm{C}=0.4 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=40 \mathrm{mAdc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 2}=0.2 \mathrm{Adc}\right) \end{aligned}$ | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | tfi |  | $\begin{aligned} & 125 \\ & 120 \end{aligned}$ | $\stackrel{200}{-}$ | ns |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Storage Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\text {si }}$ |  | 0.7 0.8 | $\stackrel{1.25}{-}$ | $\mu \mathrm{s}$ |
| Crossover Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\mathrm{C}}$ |  | 110 110 | 200 <br> - | ns |
| Fall Time | $\begin{aligned} & \left(\mathrm{I} \mathrm{C}=1.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=0.2 \mathrm{Adc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 2}=0.5 \mathrm{Adc}\right) \end{aligned}$ | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | tfi |  | 110 120 | $\stackrel{175}{-}$ | ns |
| Storage Time |  | $\left(\mathrm{T} C=125^{\circ} \mathrm{C}\right.$ ) | $\mathrm{t}_{\mathrm{si}}$ | - | $\begin{gathered} 1.7 \\ 2.25 \end{gathered}$ | $2.75$ | $\mu \mathrm{s}$ |
| Crossover Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $t_{c}$ |  | 180 210 | 300 <br> - | ns |
| Fall Time | $\begin{aligned} & \left(\mathrm{I}_{\mathrm{C}}=0.8 \mathrm{Adc}, \mathrm{I}_{\mathrm{B} 1}=160 \mathrm{mAdc}\right. \\ & \left.\mathrm{I}_{\mathrm{B} 2}=160 \mathrm{mAdc}\right) \end{aligned}$ | $\left(T^{\text {C }} \mathrm{C}=125^{\circ} \mathrm{C}\right)$ | tfi | 70 | $\overline{180}$ | $\underline{170}$ | ns |
| Storage Time |  | $\left(\mathrm{T} C=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\mathrm{si}}$ | 2.6 | $\overline{4.2}$ | 3.8 | $\mu \mathrm{s}$ |
| Crossover Time |  | $\left(\mathrm{T}_{\mathrm{C}}=125^{\circ} \mathrm{C}\right)$ | $\mathrm{t}_{\mathrm{c}}$ | - | 190 350 | 300 <br> - | ns |

## BUL44

TYPICAL STATIC CHARACTERISTICS


Figure 1. DC Current Gain at 1 Volt


Figure 3. Collector Saturation Region


Figure 5. Base-Emitter Saturation Region


Figure 2. DC Current Gain at 5 Volts


Figure 4. Collector-Emitter Saturation Voltage


Figure 6. Capacitance

TYPICAL SWITCHING CHARACTERISTICS
(IB2 = IC/2 for all switching)


Figure 7. Resistive Switching, ton


Figure 9. Inductive Storage Time, $\mathbf{t}_{\mathbf{s i}}$


Figure 11. Inductive Switching, $t_{\mathrm{C}}$ and $\mathrm{t}_{\mathrm{fi}} \mathrm{I}_{\mathrm{C}} / \mathrm{I}_{\mathrm{B}}=5$


Figure 8. Resistive Switching, $\mathbf{t}_{\text {off }}$


Figure 10. Inductive Storage Time


Figure 12. Inductive Switching, $t_{\text {C }}$ and $t_{f i} I_{C} / I_{B}=10$

TYPICAL SWITCHING CHARACTERISTICS
( $\mathrm{IB}_{\mathrm{B}}=\mathrm{IC} / 2$ for all switching)


Figure 13. Inductive Fall Time


Figure 14. Inductive Crossover Time

GUARANTEED SAFE OPERATING AREA INFORMATION


Figure 15. Forward Bias Safe Operating Area


Figure 17. Forward Bias Power Derating
There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $\mathrm{I}_{\mathrm{C}}-\mathrm{V}_{\mathrm{CE}}$


Figure 16. Reverse Bias Switching Safe Operating Area
limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate. The data of figure 15 is based on $\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C} ; \mathrm{T}_{\mathrm{J}(\mathrm{PK})}$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to $10 \%$ but must be derated when $\mathrm{T}_{\mathrm{C}}>25^{\circ} \mathrm{C}$. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown on figure 15 may be found at any case temperature by using the appropriate curve on figure $17 . \mathrm{T}_{\mathrm{J}}(\mathrm{PK})$ may be calculated from the data in figure 20. At any case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown. For inductive loads, high voltage and current must be sustained simultaneously during turn-off with the base-to-emitter junction reverse-biased. The safe level is specified as a reverse-biased safe operating area (Figure 16). This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode.


TIME
Figure 18. Dynamic Saturation Voltage Measurements


Figure 19. Inductive Switching Measurements


Table 1. Inductive Load Switching Drive Circuit
TYPICAL THERMAL RESPONSE


Figure 20. Typical Thermal Response $\left(Z_{\theta J C}(t)\right)$ for BUL44

## PACKAGE DIMENSIONS

TO-220AB
CASE 221A-09
ISSUE AA


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

|  | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | ---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 0.570 | 0.620 | 14.48 | 15.75 |
| B | 0.380 | 0.405 | 9.66 | 10.28 |
| C | 0.160 | 0.190 | 4.07 | 4.82 |
| D | 0.025 | 0.035 | 0.64 | 0.88 |
| F | 0.142 | 0.147 | 3.61 | 3.73 |
| G | 0.095 | 0.105 | 2.42 | 2.66 |
| H | 0.110 | 0.155 | 2.80 | 3.93 |
| J | 0.018 | 0.025 | 0.46 | 0.64 |
| K | 0.500 | 0.562 | 12.70 | 14.27 |
| L | 0.045 | 0.060 | 1.15 | 1.52 |
| N | 0.190 | 0.210 | 4.83 | 5.33 |
| Q | 0.100 | 0.120 | 2.54 | 3.04 |
| R | 0.080 | 0.110 | 2.04 | 2.79 |
| S | 0.045 | 0.055 | 1.15 | 1.39 |
| T | 0.235 | 0.255 | 5.97 | 6.47 |
| $\mathbf{U}$ | 0.000 | 0.050 | 0.00 | 1.27 |
| V | 0.045 | --- | 1.15 | --- |
| $\mathbf{Z}$ | --- | 0.080 | --- | 2.04 |

SWITCHMODE is a trademark of Semiconductor Components Industries, LLC.

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

## PUBLICATION ORDERING INFORMATION

Literature Fulfillment:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA

Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: ONlit@hibbertco.com
N. American Technical Support: 800-282-9855 Toll Free USA/Canada

JAPAN: ON Semiconductor, Japan Customer Focus Center 4-32-1 Nishi-Gotanda, Shinagawa-ku, Tokyo, Japan 141-0031 Phone: 81-3-5740-2700
Email: r14525@onsemi.com
ON Semiconductor Website: http://onsemi.com
For additional information, please contact your local Sales Representative.

